



SHENZHEN HAOLIN ELECTRONICS TECHNOLOGY CO., LTD

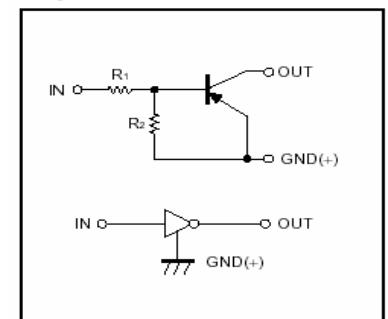
Digital transistors (built-in resistors)

DTA124EE/DTA124EUA/DTA124ECA

DTA124EKA/DTA124ESA

DIGITAL TRANSISTOR (PNP)

● Equivalent circuit

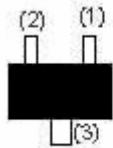


Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

PIN CONNECTIONS AND MARKING

DTA124EE

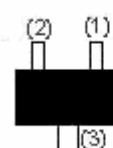


1.IN
2.GND
3.OUT

SOT-523

Addreviated symbol: 15

DTA124EUA

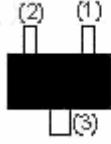


1.IN
2.GND
3.OUT

SOT-323

Addreviated symbol: 15

DTA124EKA

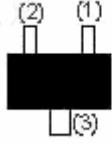


1.IN
2.GND
3.OUT

SOT-23-3L

Addreviated symbol: 15

DTA124ECA

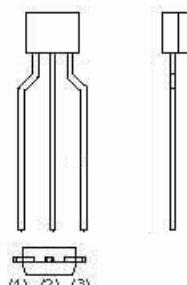


1.IN
2.GND
3.OUT

SOT-23

Addreviated symbol: 15

DTA124ESA



1.GND
2.OUT
3.IN

TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA124E)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}			-50			V
Input voltage	V _{IN}		-40~10				V
Output current	I _O			-30			mA
	I _{C(MAX)}			-100			
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{stg}			-55~150			°C

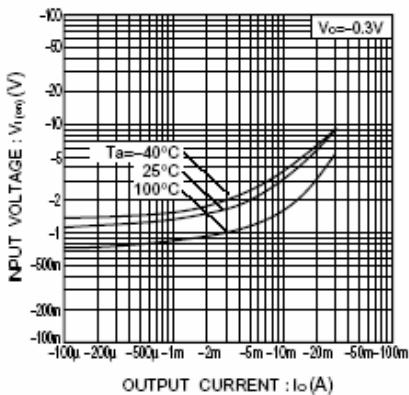
Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.5	V	V _{CC} =-5V ,I _O =-100μA
	V _{I(on)}	-3				V _O =-0.2V ,I _O =-5 mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-10mA/-0.5mA
Input current	I _I			-0.36	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V ,V _I =0
DC current gain	G _I	56				V _O =-5V ,I _O =-5mA
Input resistance	R _I	15.4	22	28.6	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =-10V ,I _O =-5mA,f=100MHz

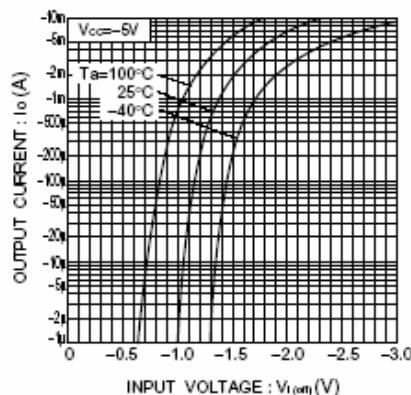
Typical Characteristics

DTA124EE/EUA/EKA/ESA/ECA

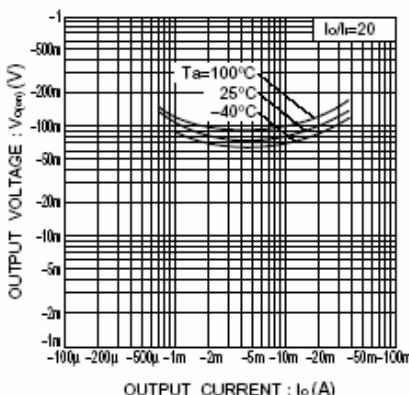
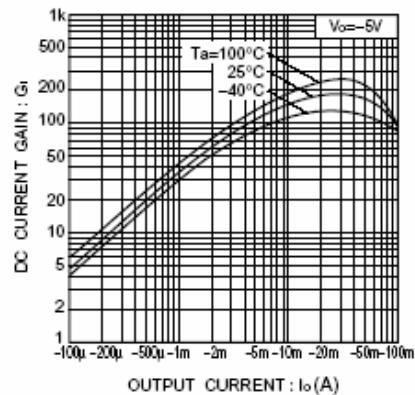
●Electrical characteristic curves



(ON characteristics)



(OFF characteristics)



(Io/Ii = 20)